

10CS32

Third Semester B.E. Degree Examination, June/July 2016 **Electronic Circuits**

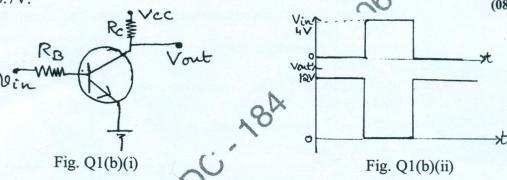
Time: 3 hrs.

Max. Marks:100

Note: Answer any FIVE full questions, selecting atleast TWO questions from each part.

PART - A

- With the help of common emitter amplifier configuration, explain the criteria for selection of a suitable operating point and the factors affecting its stability. (08 Marks)
 - Fig. Q1(b)(i) shows the transistor as an inverting switch with the desired output waveform for the given input waveform as shown in Fig. Q1(b)(ii). Find the value of V_{CC}, R_C and R_B given that β = 80, $I_{C(sat)}$ = 10 mA, the output voltage V_{out} when the transistor is off is 12 V, $V_{BE} = 0.7V.$ (08 Marks)



Explain the gate triggering characteristics of an SCR.

(04 Marks)

- Draw and explain the working of D-MOSFET with the help of drain current and transconductance curve. When the voltage is applied to the gate of a P-Channel D-MOSFET, does the current flow depleted or enhanced?
- b. Fig. Q2(b) shows a circuit using E MOSFET given that the threshold voltage for the dhy confidential MOSFET is 2 V and $I_{d(on)} = 6$ mA for $V_{GS(on)} = 5V$, determine the volume of the operating (08 Marks)

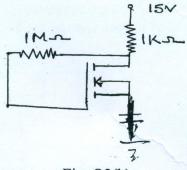


Fig. Q2(b)

What are photodiodes? Explain with VI characteristics. 3

(05 Marks)

- Determine the cut-off wave length for silicon and germanium photodiodes, given that their Bandgap energies are 1.1 ev and 0.72 ev, respectively, at 25°C. How will the cut off wave length change when the operating temperature change form 25°C to 200°C? (05 Marks)
- c. Write short note on:
 - i) Cathode ray tube display
 - ii) Emerging display technologies.

(10 Marks)

sorily draw diagonal cross lines on the remaining blank pr my revealing of identification, appeal to evaluator and /or equations written eg, 42+8 = 50, w. Important Note: 1. On completing your answers, com

le treated as malpractice



- 4 a. Explain how the h-parameters are determined by making use of transistor's input and output characteristics. (10 Marks)
 - b. Carryout the analysis of a transistor amplifier operating in common emitter fixed bias configuration with suitable derivations. (10 Marks)

PART - B

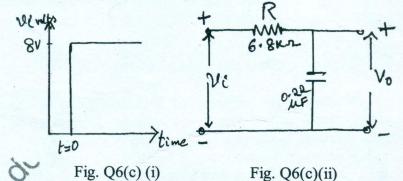
- 5 a. Distinguish between class A, class B, Class C, class D, class AB amplifiers interns of conduction angle, operating region, application and efficiency.
 - b. Explain all four feedback topologies with appropriate circuit diagrams.

An amplifier has a open – loop voltage gain $A_v = 1000 \pm 100$. It is required to have an amplifier whose voltage gain varies by no more than $\pm 0.1\%$.

- i) Find the value of feedback factor B
- ii) Find gain with feedback.

(05 Marks)

- 6 a. Explain Barkhausen criteria with suitable circuit diagrams and essential conditions.
 - b. Explain with a neat connection diagram and waveforms how IC555 timer is used as the astable multivibrator. (08 Marks)
 - c. A step input of amplitude 8 volts is applied to a RC low pass circuit shown in Fig. Q6(c)(i) and Fig. Q6(c)(ii) below. Determine the output voltage at end of: i) 2m/sec ii) 5m/sec iii) Find upper cut-off frequency f_w and rise time t_r.



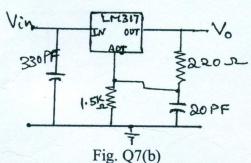
7 a. Write a note on 3 terminal voltage regulator.

(05 Marks)

(10 Marks)

b. Determine the regulated output voltage for LM 317 voltage regulator shown in Fig. Q7(b).

(05 Marks)



- c. What are switching regulators? Describe the basic topology of Boost regulator.
- 8 a. Differentiate ideal Op-Amp and practical Op-Amps. (05 Marks)
 - b. Discuss performance parameters of operational amplifiers.
 c. Explain Op-Amp as peak detector circuit.
 (10 Marks)
 (05 Marks)

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